
	<h2>SI7900AEDN-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI7900AEDN-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 20V 6A PPAK 1212-8</p> <p>Datenblätter:  SI7900AEDN-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 29962 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7900AEDN-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 20V 6A PPAK 1212-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	29962 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.5W
Verpackung / Gehäuse	PowerPAK® 1212-8 Dual
Supplier Device-Gehäuse	PowerPAK® 1212-8 Dual
Typ FET	2 N-Channel (Dual) Common Drain
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A
Rds On (Max) @ Id, Vgs	26 mOhm @ 8.5A, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Original-Reel®

SI7900AEDN-T1-GE3 ist neu im Original, Suche SI7900AEDN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7900AEDN-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7900AEDN-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI7900EDM VISHAY VISHAY DFN	 SI7900AEDN-T1 VISHAY SI7900AEDN-T1 VISHAY	 SI7900AEDN-T1-E3 Vishay / Siliconix MOSFET 2N-CH 20V 6A 1212-8	 SI7900DN VISHAY VISHAY QFN-8
 SI7900AEDN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 6A PPAK 1212-8	 SI7900EDN-1 VISHAY VISHAY QFN	 SI7900AEDN-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 6A 1212-8	 SI7900AEDN SI SI7900AEDN SI

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Mehr

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|  SI7888DP-T1-E3 |  SI7888DP-T1-GE3 |  SI7888DP-T1-GE3 |  SI7892ADP-T1-E3 |  SI7892ADP-T1-GE3 |
|  SI7892ADP-T1-GE3 |  SI7892BDP-T1-E3 |  SI7892BDP-T1-E3 |  SI7892BDP-T1-GE3 |  SI7892BDP-T1-GE3 |
|  SI7892DP |  SI7892DP-T1 |  SI7892DP-T1-E3 |  SI7892DP-T1-GE3 |  SI7898DP |
|  SI7898DP-T1-E3 |  SI7898DP-T1-E3 |  SI7898DP-T1-GE3 |  SI7898DP-T1-GE3 |  SI7900ADN |
|  SI7900AEDN |  SI7900AEDN-T1 |  SI7900AEDN-T1-E3 |  SI7900AEDN-T1-E3 |  SI7900AEDN-T1-GE3 |
|  SI7900EDN |  SI7900EDN-T1 |  SI7900EDN-T1-E3 |  SI7900EDN-T1-GE3 |  SI7901EDN-T1 |
|  SI7901EDN-T1-E3 |  SI7901EDN-T1-E3 |  SI7904BDN-T1-E3 |  SI7904BDN-T1-E3 |  SI7904BDN-T1-GE3 |
|  SI7904BDN-T1-GE3 |  SI7904DN |  SI7904DN-T1 |  SI7904DN-T1-E3 |  SI7904DN-T1-E3 |
|  SI7904DN-T1-GE3 |  SI7904DN-T1-GE3 |  SI7905DN-T1-GE3 |  SI7905DN-T1-GE3 |  SI7909DN-T1-E3 |
|  SI7909DN-T1-E3 |  SI7909DN-T1-GE3 |  SI7909DN-T1-GE3 |  SI7911DN |  SI7911DN-T1-E3 |

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